

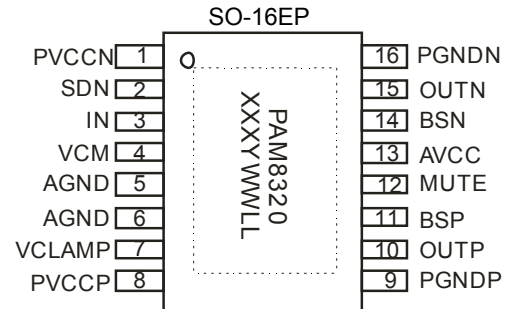
## Description

The PAM8320 is an efficient 20W mono Class-D audio power amplifier, designed to drive speakers as low as 4Ω in a bridge-tied-load configuration. Due to the low power dissipation and high efficiency of up to 95%, the device can be used without any external heat sink whilst playing music.

The PAM8320 features short circuit protection, thermal shutdown, over voltage protection and under voltage lock-out.

The PAM8320 is available in a SO-16EP package.

## Pin Assignments



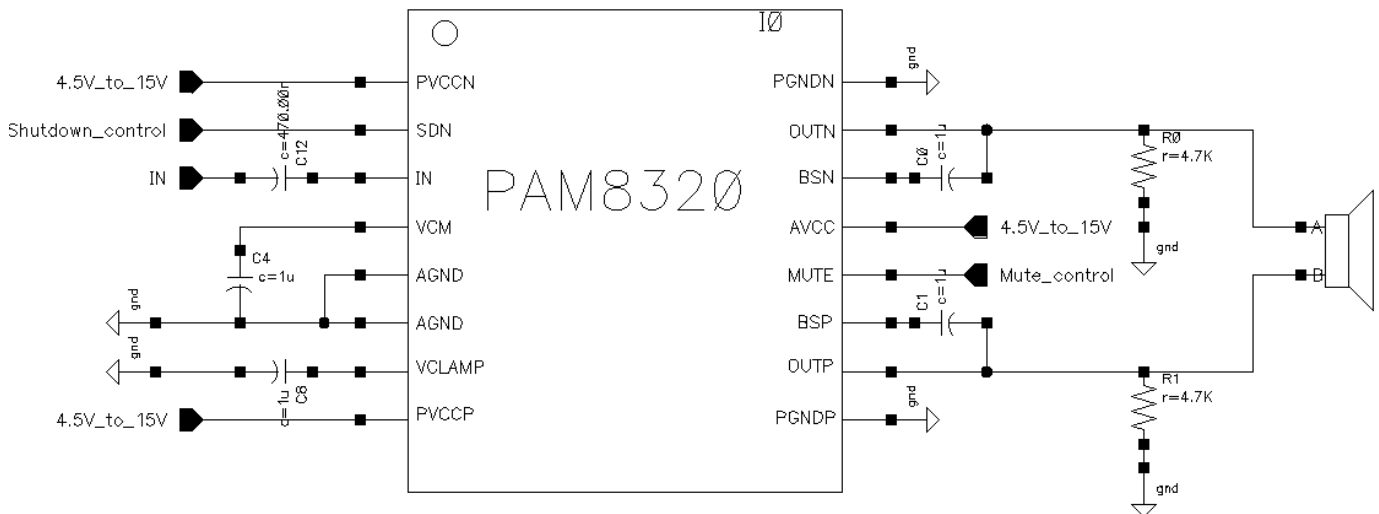
## Features

- Operates from 4.5V to 15V
- 20W into 4Ω BTL Load from 12V Supply
- Single-Ended Analog Input
- No Pop Noise for Start-up and Shut-down Sequences
- Internal Oscillator (No External Components Required)
- High Efficient Class-D Operation Eliminates Need for Heat Sinks
- Thermal and Short-Circuit Protection with Auto Recovery
- Over Voltage Protection and Under Voltage Lock-out
- Space-Saving Surface-Mount SO-16EP Package
- Pb-Free Package

## Applications

- PC Speaker
- Blue Tooth Speaker
- Home Sound Systems
- Active Speakers
- Docking stations

## Typical Applications Circuit

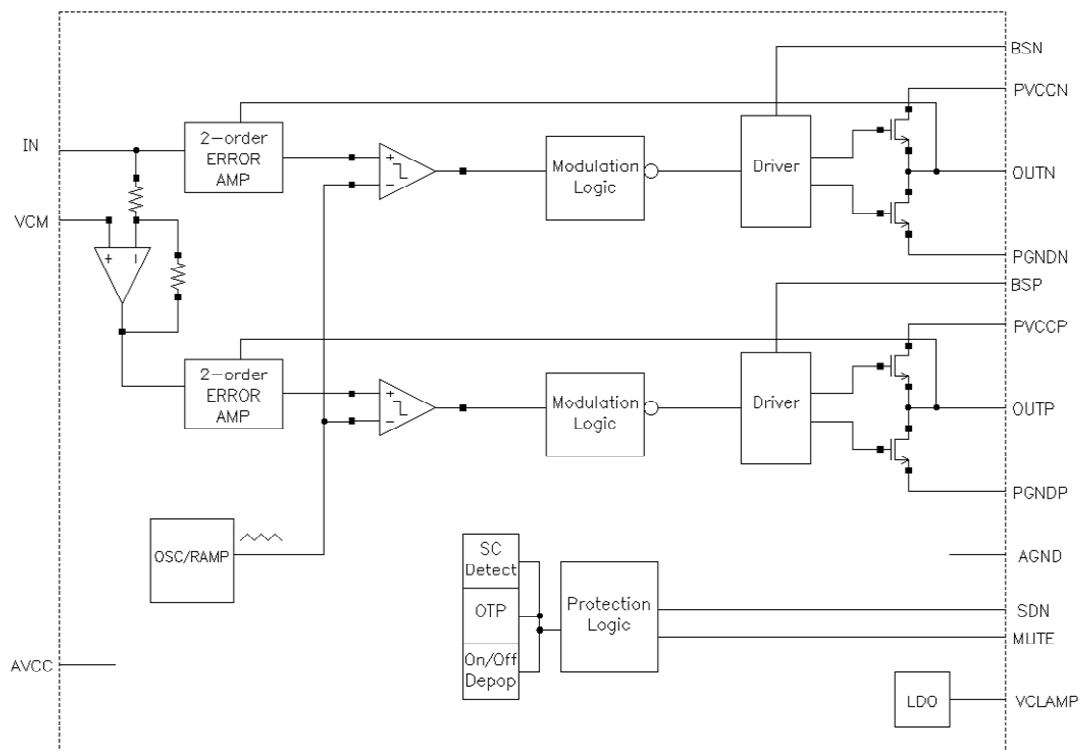


**Pin Descriptions**

Pin	Name	I/O/P	Description
1	PVCCN	P	Power supply for negative H-bridge, not connected to PVCCP or AVCC
2	SDN	I	Shutdown signal for IC (low=shutdown, high=operational). TTL logic levels with compliance to AVCC
3	IN	I	Audio input
4	VCM	O	Reference for analog cells
5,6	AGND	P	Analog ground for digital/analog cells in core
7	VCLAMP	P	Internally generated voltage supply for bootstrap. Not to be used as a supply or connected to any component other than the decoupling capacitor.
8	PVCCP	P	Power supply for positive H-bridge, not connected to PVCCN or AVCC
9	PGNDP	P	Power ground for positive H-bridge
10	OUTP	O	Positive BTL output
11	BSP	I/O	Bootstrap terminal for high-side drive of positive BTL output
12	MUTE	I	A logic high on this pin disables the outputs. A low on this pin enables the outputs. TTL logic levels with compliance to AVCC
13	AVCC	P	High-voltage analog power supply
14	BSN	I/O	Bootstrap terminal for high-side drive of negative BTL output
15	OUTN	O	Negative BTL output
16	PGNDN	P	Power ground for negative H-bridge

New Product

**Functional Block Diagram**



**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter	Rating	Unit
Supply Voltage (V <sub>CC</sub> )	18	V
Logic Input Voltage (SDN, MUTE)	-0.3 to V <sub>CC</sub> +0.3	V
Analog Input Voltage (I <sub>N</sub> )	-0.3 to 5.5	V
Storage Temperature	-65 to +150	°C
Maximum Junction Temperature	+150	°C
Junction to ambient thermal resistance	40	°C/W

**Recommended Operating Conditions** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

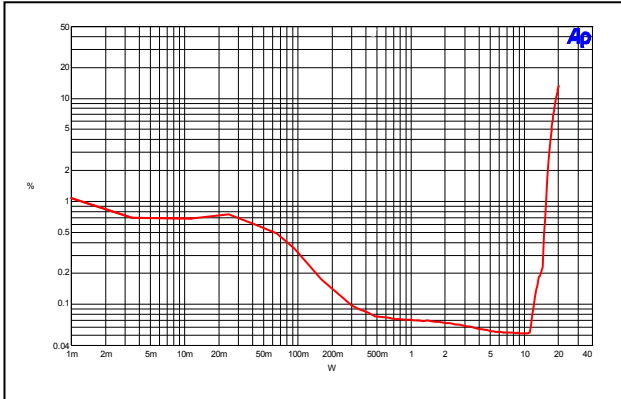
Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.5	15	V
T <sub>A</sub>	Operating Ambient Temperature Range	-40	+85	°C
T <sub>J</sub>	Junction Temperature Range	-40	+125	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, V<sub>CC</sub> = 12V, Gain = 20dB, R<sub>L</sub> = L(33μH) + R + L(33μH), unless otherwise noted.)

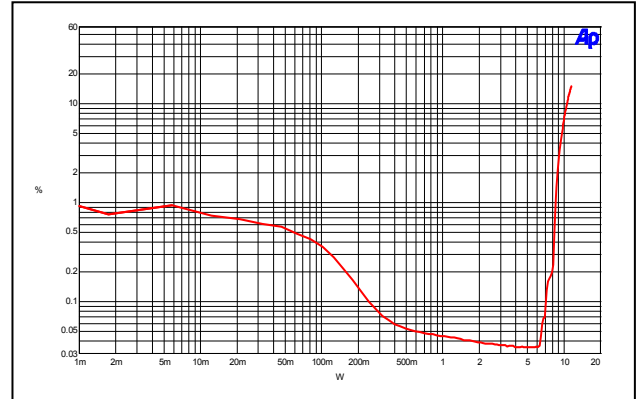
Symbol	PARAMETER	Test Conditions	MIN	TYP	MAX	Units
VOS	Class-D output offset voltage(measured differently)	V <sub>i</sub> =0V, A <sub>v</sub> =20dB	—	20	100	mV
I <sub>CC(q)</sub>	Quiescent supply current	SDN=3.0V, MUTE=0V, No Load	—	15	30	mA
I <sub>CC(MUTE)</sub>	Quiescent supply current in mute mode	MUTE=2.0V, No load	—	8	20	mA
I <sub>CC(SDN)</sub>	Quiescent current in shutdown mode	SDN=0.5V, No load	—	20	40	uA
R <sub>ds(on)</sub>	Drain-source on-state resistance	I <sub>O</sub> =0.5A	—	150	—	mΩ
P <sub>SRR</sub>	Power Supply Rejection Ratio	V <sub>ripple</sub> =200mVpp, f=1kHz,gain=20dB	—	-60	—	dB
P <sub>O</sub>	Output Power at 1% THD+N	f=1kHz	—	15	—	W
	Output Power at 10% THD+N	f=1kHz	—	20	—	
THD+N	Total harmonic distortion + noise	f=1kHz, P <sub>O</sub> =7W	—	0.05	—	%
V <sub>n</sub>	Output integrated noise floor	20Hz to 22kHz, A-weighted, Gain=20dB	—	300	—	uV
SNR	Signal-to-noise ratio	Max output at THD+N<1%, f=1kHz, Gain=20dB	—	95	—	dB
OTP	Thermal trip point	—	—	+160	—	°C
OTH	Thermal hysteresis	—	—	+40	—	°C
f <sub>osc</sub>	Oscillator frequency	—	—	300	—	kHz
V <sub>IH_SDN</sub>	SDN Input High	—	3	—	—	—
V <sub>IL_SDN</sub>	SDN Input Low	—	—	—	0.5	—
V <sub>IH_MUTE</sub>	MUTE Input High	—	2	—	—	—
V <sub>IL_MUTE</sub>	MUTE Input Low	—	—	—	0.5	—

**Performance Characteristics** (@ $T_A = +25^\circ\text{C}$ ,  $V_{DD} = 12\text{V}$ , Gain = 20dB,  $R_L = L(33\mu\text{H}) + R + L(33\mu\text{H})$ , unless otherwise noted.)

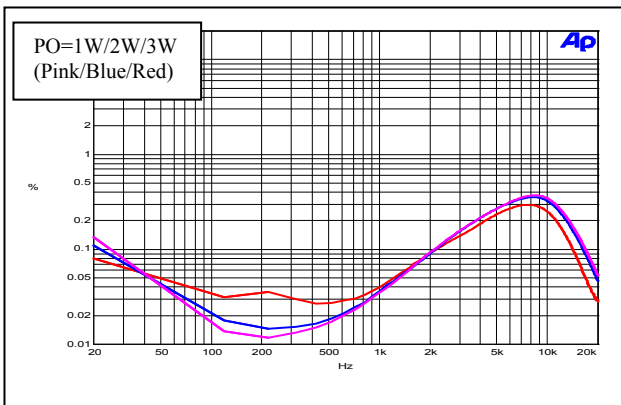
THD+N Vs. Output Power (RL=4Ω)



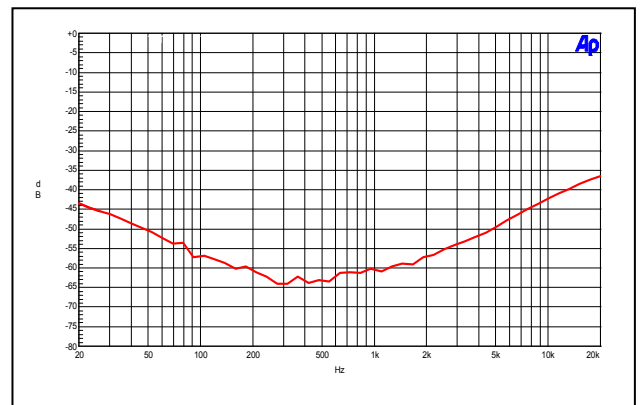
THD+N Vs. Output Power (RL=8Ω)



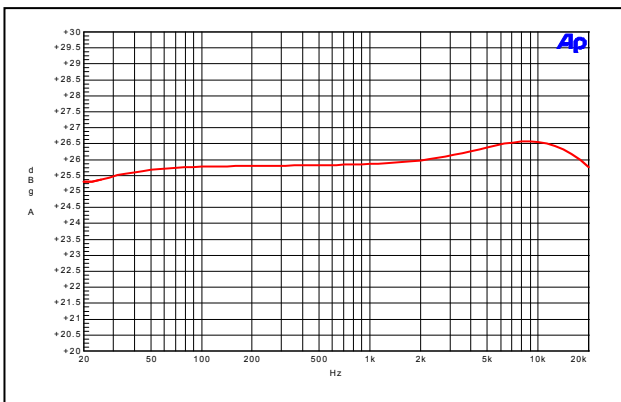
THD+N Vs. Frequency



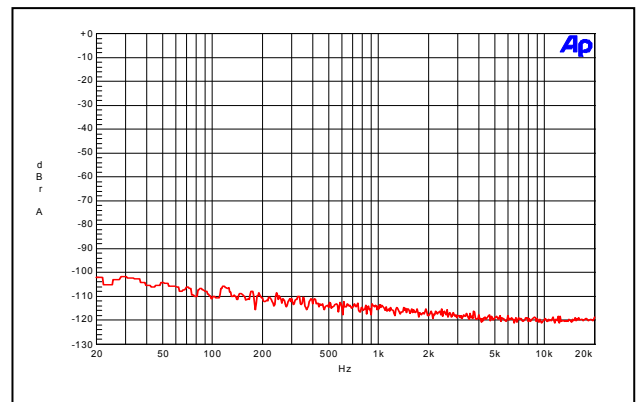
PSRR Vs. Frequency



Frequency Response



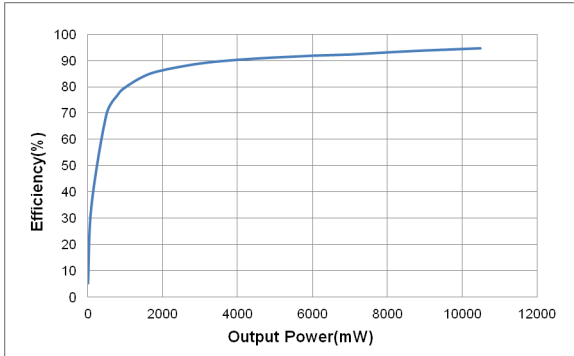
Noise Floor



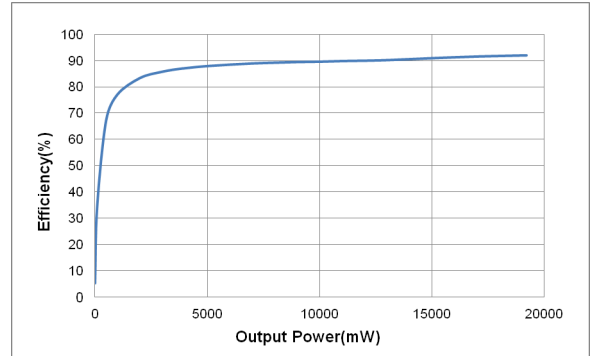
**Performance Characteristics** (@ $T_A=25^{\circ}\text{C}$ ,  $V_{DD}=12\text{V}$ , Gain=20dB,  $R_L=L(33\mu\text{H})+R+L(33\mu\text{H})$ , unless otherwise noted.)

New Product

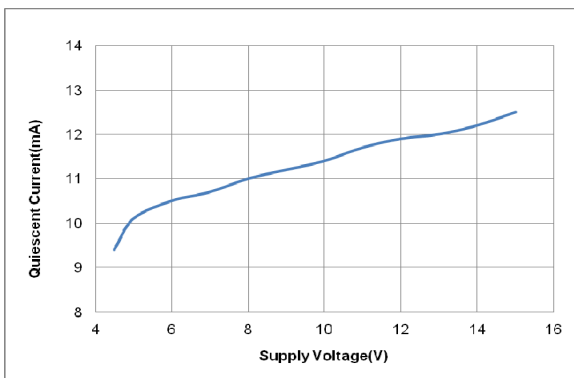
Efficiency Vs. Output Power ( $R_L=8\Omega$ )



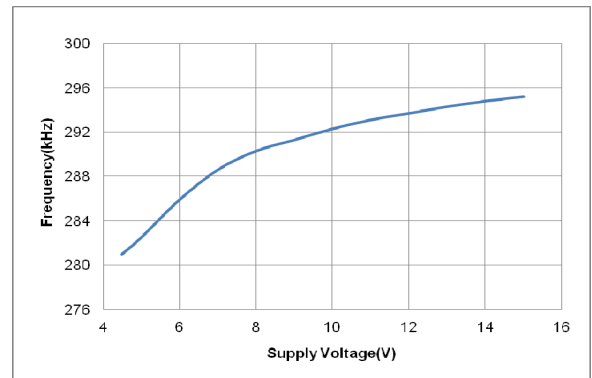
Efficiency Vs. Output Power ( $R_L=4\Omega$ )



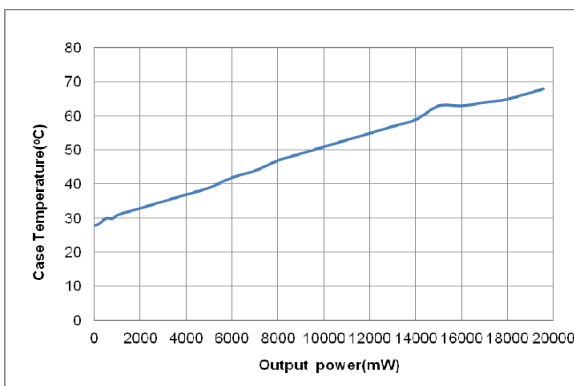
Quiescent Current Vs. Supply Voltage



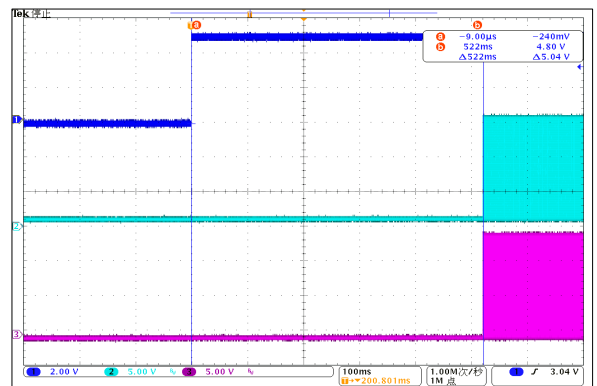
OSC Frequency Vs. Supply Voltage



Case Temperature Vs. Output Power ( $R_L=4\Omega$ )



Turn-on Response



## Application Information

### Input Capacitors (Ci)

In the typical application, an input capacitor Ci, is required to allow the amplifier to bias the input signal to the proper DC level for optimum operation. In this case, Ci and the minimum input impedance Ri form a high-pass filter with the corner frequency determined in the follow equation:

$$f_c = \frac{1}{(2\pi R_i C_i)}$$

It is important to consider the value of Ci as it directly affects the low frequency performance of the circuit. For example, when Ri is 40kΩ and the specification calls for a flat bass response are down to 20Hz. The equation is reconfigured as followed to determine the value of Ci:

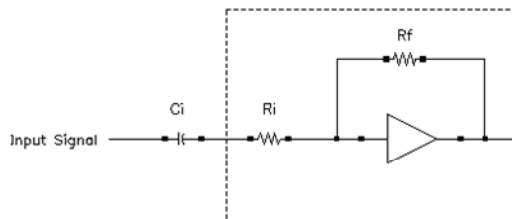
$$C_i = \frac{1}{(2\pi R_i f_c)}$$

When input resistance variation is considered Ci is 200nF, so one would likely choose a value of 220nF. A further consideration for this capacitor is the leakage path from the input source through the input network (Ci, Ri and Rf) to the load. This leakage current creates a DC offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the DC level is held at VDD/2, which is likely higher than the source DC level. Please note that it is important to confirm the capacitor polarity in the application.

### Input Resistance

The value of the input resistance (Ri) of the amplifier is 40kΩ ±20%. If a single capacitor is added to the input of the high-pass filter the -3dB cutoff frequency can be calculated using equation:

$$f_c = \frac{1}{(2\pi R_i C_i)}$$



### Gain Formula with External Input Resistor

The default gain of PAM8320 is 26dB. The gain can be reduced by adding one external resistor between input decoupling capacitor and IN PIN. The gain formula is as below:

$$A_v = \frac{20}{1 + 14 \times \frac{R_x}{400k}}$$

Note: Rx is external input resistor

### Power and Heat Dissipation

Speakers must be chosen to withstand the large output power from the PAM8320, otherwise speaker damage may occur.

Heat dissipation is very important when the device works in full power operation. Two factors affect the heat dissipation, the efficiency of the device that determines the dissipation power and the thermal resistance of the package that determines the heat dissipation capability.

The PAM8320 class-D amplifier is highly efficiency and should not need heat sink. Operating at higher powers a heat sink still may not be necessary if the PCB is carefully designed to achieve good thermal dissipation.

### Dual-Side PCB

To achieve good heat dissipation the PCB's copper plate should be thicker than 35um and the copper plate on both sides of the PCB should be utilized for heat sink.

The thermal pad on the bottom of the device should be soldered to the plate of the PCB and via holes (usually 9 to 16) should be drilled in the PCB area under the device. Deposited copper on the vias should be thick enough so that the heat can be dissipated to the other side of the plate. There should be no insulation mask on the other side of the copper plate. More vias can and should be added to the PCB around the device for further thermal optimization.

### How to Reduce EMI

Most applications require a ferrite bead filter for EMI elimination shown at Figure 1. The ferrite filter reduces EMI around 1MHz and higher. When selecting a ferrite bead it should be chosen with high impedance at high frequencies but low impedance at low frequencies.

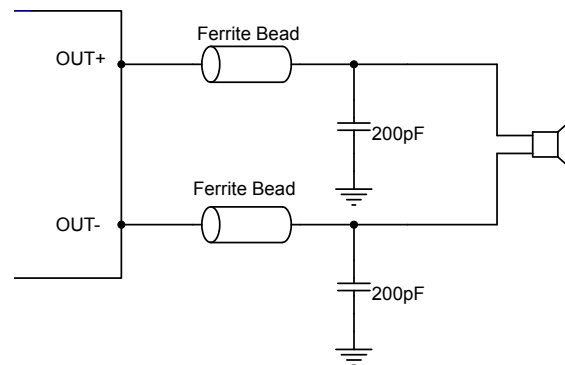


Figure 1: Ferrite Bead Filter to Reduce EMI

### Shutdown Operation

The PAM8320 employs a shutdown operation mode to reduce supply current to the absolute minimum level during periods of non-use to save power. The SDN input terminal should be pull high during normal operation. Pulling SDN low causes the outputs to be muted and the amplifier enters a low-current state. SDN should never be left unconnected.

### Anti-POP and Anti-Click Circuitry

The PAM8320 contains circuitry to minimize turn-on and turn-off transients or “click and pops”, where turn-on refers to either power supply turn-on or device recover from shutdown mode. When the device is turned on, the amplifiers are internally muted. An internal current source ramps up the internal reference voltage. The device will remain in mute mode until the reference voltage reach half supply voltage. As soon as the reference voltage is stable, the device will begin full operation. For the best power-off pop performance, the amplifier should be set in shutdown mode prior to removing the power supply voltage.

### Internal Bias Generator Capacitor Selection

The internal bias generator (VCM) provides the internal bias for the preamplifier stage. The external input capacitors and this internal reference allow the inputs to be biased within the optimal common-mode range of the input preamplifiers.

The selection of the capacitor value on the VCM terminal is critical for achieving the best device performance. During startup or recovery from shutdown state the VCM capacitor determines the rate at which the amplifier starts up. The startup time is not critical for the best de-pop performance since any heard pop sound is the result of the class-D output switching-on other than that of the startup time. However, at least a 0.47μF capacitor is recommended for the VCM capacitor.

Another function of the VCM capacitor is to bypass high frequency noise on the internal bias generator.

### Power Supply Decoupling, CS

The PAM8320 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) as low as possible. Power supply decoupling also prevents the oscillations causing by long lead length between the amplifier and the speaker.

Optimum decoupling is achieved by using two different types of capacitors that target different types of noise on the power supply leads. Higher frequency transients, spikes or digital hash should be filtered with a good low equivalent-series-resistance (ESR) ceramic capacitor with a value of typically 0.1 $\mu$ F. This capacitor should be placed as close as possible to the PVCC pin of the device. Lower frequency noise signals should be filtered with a large ceramic capacitor of 470 $\mu$ F or greater. It's recommended to place this capacitor near the audio power amplifier. The 10 $\mu$ F capacitor also serves as a local storage capacitor for supplying current during large signal transients on the amplifier outputs.

### BSN and BSP Capacitors

The half H-bridge output stages use NMOS transistors therefore requiring bootstrap capacitors for the high side of each output to turn on correctly. A ceramic capacitor 220nF or more rated for over 25V must be connected from each output to its corresponding bootstrap input. Specifically, one 220nF capacitor must be connected from OUTN to BSN and another 220nF capacitor from OUTP to BSP. It is recommended to use 1 $\mu$ F BST capacitor to replace 220nF for lower than 100Hz applications.

### VCLAMP Capacitors

To ensure that the maximum gate-to-source voltage for the NMOS output transistors is not exceeded, an internal regulator is used to clamp the gate voltage. A 1 $\mu$ F capacitor must be connected from VCLAMP to ground and must be rated for at least 25V. The voltages at the VCLAMP terminals vary with VCC and may not be used to power any other circuitry.

### Using low-ESR Capacitors

Low-ESR capacitors are recommended throughout this application section. A real (with respect to ideal) capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance the more the real capacitor behaves as an ideal capacitor.

### Short-circuit Protection

The PAM8320 has short circuit protection circuitry on the outputs to prevent damage to the device when output-to-output shorts (BTL mode), output-to-GND shorts, or output-to-VCC shorts occur. Once a short-circuit is detected on the outputs, the output drive is immediately disabled. This is not a latched fault, if the short is removed the normal operation is restored.

### Thermal Protection

Thermal protection prevents the device from damage. When the internal die temperature exceeds a typical of 160°C the device will enter a shutdown state and the outputs are disabled. This is not a latched fault, once the thermal fault is cleared and the temperature of the die decreased by 40°C the device will restart with no external system interaction.

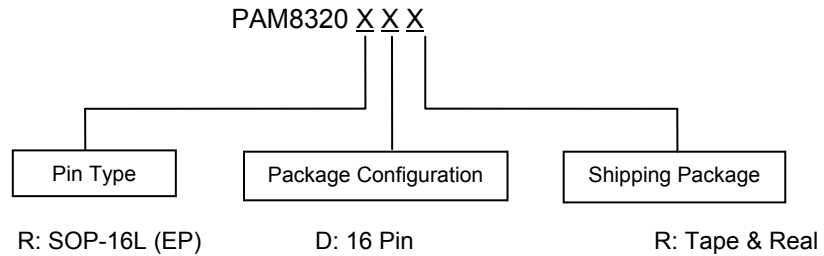
### Over Voltage Protection and Under Voltage Lock-out (OVP and UVLO)

An over voltage protection (OVP) circuit is integrated in PAM8320, when the supply voltage is over 18V the OVP is active and then the output stage is disabled. The PAM8320 will auto recovery when the supply voltage is lower than the OVP threshold.

The PAM8320 incorporates circuitry designed to detect low supply voltage. When the supply voltage drops to 4.4V or below, the PAM8320 goes into a state of shutdown. When the supply voltage is higher than 4.5V normal operation is resumed.

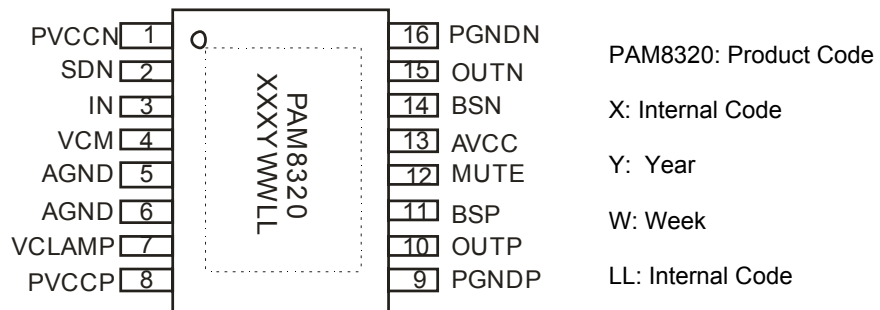


## Ordering Information



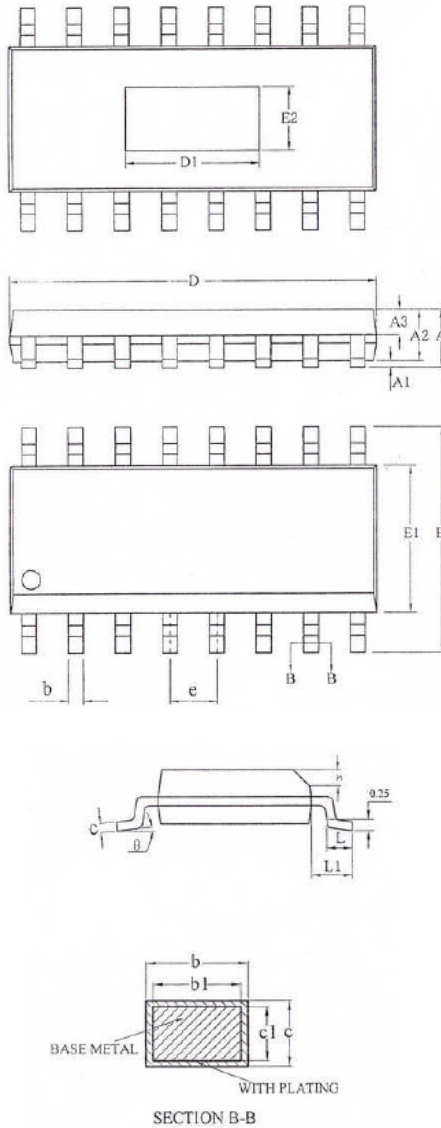
Part Number	Package	Standard Package
PAM8320RDR	SO-16EP	2,500Units/Tape&Real

## Marking Information



**Package Outline Dimensions** (All dimensions in mm.)

Package: SO-16EP



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	—	—	1.75
A1	0.05	—	0.225
A2	1.30	1.40	1.50
A3	0.60	0.65	0.70
b	0.39	—	0.48
b1	0.38	0.41	0.43
c	0.21	—	0.26
c1	0.19	0.20	0.21
D	9.70	9.90	10.10
E	5.80	6.00	6.20
E1	3.70	3.90	4.10
e	1.27BSC		
h	0.25	—	0.50
L	0.50	—	0.80
L1	1.05BSC		
0	0	—	8°
D1	3.86REF		
E2	1.67REF		
1. 千分位尺寸 (mil)	95*180		

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